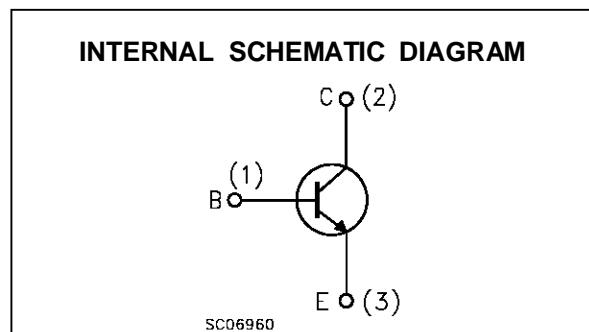
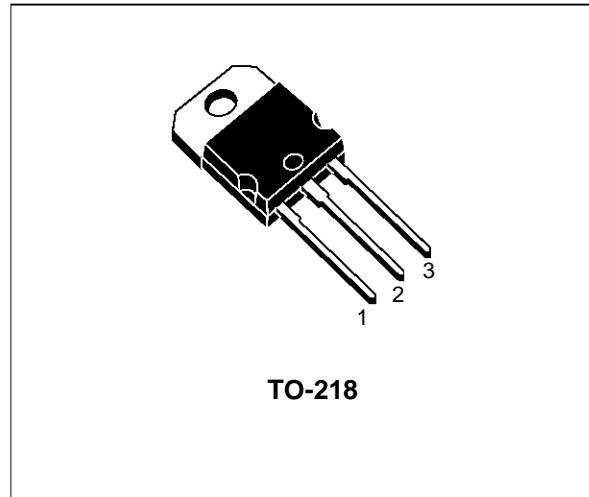


## SILICON NPN SWITCHING TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPE
- HIGH VOLTAGE HIGH SPEED TRANSISTOR SUITED FOR USE ON THE 220 AND 380V MAINS
- SUITABLE FOR SWITCH MODE POWER SUPPLY UPS, DC AND AC MOTOR CONTROL



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CEV}$	Collector-Emitter Voltage ( $V_{EB} = -1.5V$ )	850	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	450	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	7	V
$I_E$	Emitter Current	30	A
$I_{EM}$	Emitter Peak Current	45	A
$I_B$	Base Current	6	A
$I_{BM}$	Base Peak Current	10	A
$P_{tot}$	Total Dissipation at $T_c < 25^\circ\text{C}$	200	W
$T_{stg}$	Storage Temperature	-65 to 150	$^\circ\text{C}$
$T_j$	Max. Operating Junction Temperature	150	$^\circ\text{C}$

## BUX98P

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### THERMAL DATA

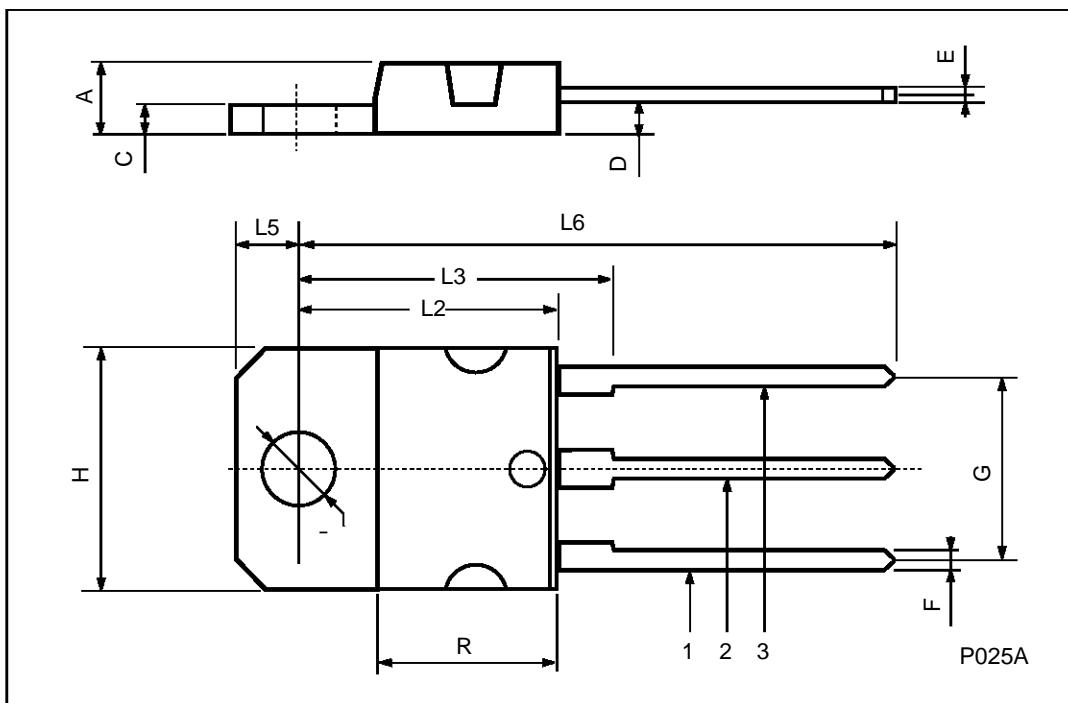
$R_{\text{thj-case}}$	Thermal Resistance Junction-case	Max	0.63	$^{\circ}\text{C/W}$
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**ELECTRICAL CHARACTERISTICS** ( $T_{\text{case}} = 25^{\circ}\text{C}$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{\text{CER}}$	Collector Cut-off Current ( $R_{\text{BE}} = 5\Omega$ )	$V_{\text{CE}} = V_{\text{CEV}}$ $V_{\text{CE}} = V_{\text{CEV}}$ $T_c = 100^{\circ}\text{C}$			0.2 1	mA mA
$I_{\text{CEV}}$	Collector Cut-off Current	$V_{\text{CE}} = V_{\text{CEV}}$ $V_{\text{BE}} = -1.5\text{V}$ $V_{\text{CE}} = V_{\text{CEV}}$ $V_{\text{BE}} = -1.5\text{V}$ $T_c = 100^{\circ}\text{C}$			0.2 1	mA mA
$I_{\text{EBO}}$	Emitter Cut-off Current ( $I_c = 0$ )	$V_{\text{EB}} = 5\text{V}$			1	mA
$V_{\text{CEO(sus)*}}$	Collector-Emitter Sustaining Voltage	$I_c = 0.2\text{A}$ $L = 25\text{mH}$	450			V
$V_{\text{EBO}}$	Emitter-Base Voltage( $I_c=0$ )	$I_E = 100\text{mA}$		7		V
$V_{\text{CE(sat)*}}$	Collector-Emitter Saturation Voltage	$I_c = 20\text{A}$ $I_B = 4\text{A}$ $I_c = 20\text{A}$ $I_B = 4\text{A}$ $T_j = 100^{\circ}\text{C}$		0.35 0.7	0.9 2	V V
$V_{\text{BE(sat)*}}$	Base-Emitter Saturation Voltage	$I_c = 20\text{A}$ $I_B = 4\text{A}$ $I_c = 20\text{A}$ $I_B = 4\text{A}$ $T_j = 100^{\circ}\text{C}$		1.05 1	1.5 1.5	V V
$dI_c/dt$	Rate of Rise of on-state Collector Current	$V_{\text{CC}} = 300\text{V}$ $I_{B1} = 6\text{A}$ $R_C = 0$ $T_p = 3\mu\text{s}$ $T_j = 100^{\circ}\text{C}$	120	160		A/ $\mu\text{s}$
$V_{\text{CE}(3\mu\text{s})}$	Collector-Emitter Dynamic Voltage	$V_{\text{CC}} = 300\text{V}$ $I_{B1} = 6\text{A}$ $R_C = 15\Omega$ $T_j = 100^{\circ}\text{C}$		4.5	8	V
$V_{\text{CE}(5\mu\text{s})}$	Collector-Emitter Dynamic Voltage	$V_{\text{CC}} = 300\text{V}$ $I_{B1} = 6\text{A}$ $R_C = 15\Omega$ $T_j = 100^{\circ}\text{C}$		2.5	4	V
$t_s$ $t_f$ $t_c$	<b>INDUCTIVE LOAD</b> Storage time Fall Time Crossover Time	$V_{\text{CC}} = 50\text{V}$ $V_{\text{clamp}} = 450\text{V}$ $I_c = 20\text{A}$ $I_B = 4\text{A}$ $V_{\text{BB}} = -5\text{V}$ $R_{\text{BB}} = 0.62\Omega$ $L_c = 0.12\text{mH}$ $T_j = 100^{\circ}\text{C}$		3 0.25 0.5	4.5 0.4 0.7	$\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
$V_{\text{CEW}}$	Maximum Collector Emitter Voltage without Snubber	$V_{\text{CC}} = 50\text{V}$ $I_{\text{CWoff}} = 30\text{A}$ $V_{\text{BB}} = -5\text{V}$ $I_{B1} = 4\text{A}$ $L_c = 0.08\text{mH}$ $R_{\text{BB}} = 0.62\Omega$ $T_j = 125^{\circ}\text{C}$	450			V

## TO-218 (SOT-93) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.7		4.9	0.185		0.193
C	1.17		1.37	0.046		0.054
D		2.5			0.098	
E	0.5		0.78	0.019		0.030
F	1.1		1.3	0.043		0.051
G	10.8		11.1	0.425		0.437
H	14.7		15.2	0.578		0.598
L2	—		16.2	—		0.637
L3		18			0.708	
L5	3.95		4.15	0.155		0.163
L6		31			1.220	
R	—		12.2	—		0.480
Ø	4		4.1	0.157		0.161



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